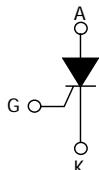
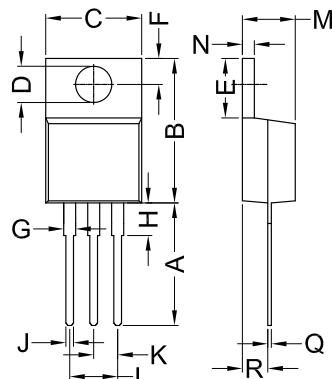


# STYN208(S) thru STYN108(S)

## Thyristor Discretes(SCRs)

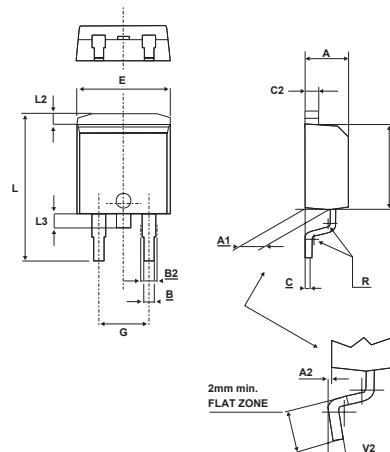


Dimensions TO-220AB



REF.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
L	5.08	BSC	0.200	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.35	0.56	0.014	0.022
R	2.29	2.79	0.090	0.110

Dimensions TO-263(D<sup>2</sup>PAK)



REF.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
C	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R	0.40		0.40		0.016	
V2	0°		8°	0°		8°

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value		Unit
I <sub>T(RMS)</sub>	RMS on-state current (180° conduction angle)		T <sub>c</sub> = 110°C	8	A
I <sub>T(AV)</sub>	Average on-state current (180° conduction angle)		T <sub>c</sub> = 110°C	5	A
I <sub>TSM</sub>	Non repetitive surge peak on-state current	tp = 8.3 ms	T <sub>j</sub> = 25°C	100	A
		tp = 10 ms		95	
I <sup>2</sup> t	I <sup>2</sup> t Value for fusing	tp = 10 ms	T <sub>j</sub> = 25°C	45	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current I <sub>G</sub> = 2 x I <sub>GT</sub> , tr £ 100 ns	F = 60 Hz	T <sub>j</sub> = 125°C	50	A/µs
I <sub>GM</sub>	Peak gate current	tp = 20 µs	T <sub>j</sub> = 125°C	4	A
P <sub>G(AV)</sub>	Average gate power dissipation		T <sub>j</sub> = 125°C	1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C
				5	V

# STYN208(S) thru STYN1008(S)

## Thyristor Discretes(SCRs)

ELECTRICAL CHARACTERISTICS ( $T_j = 25^\circ\text{C}$ , unless otherwise specified)

### ■ STANDARD

Symbol	Test Conditions		Value	Unit
$I_{GT}$	$V_D = 12 \text{ V}$ $R_L = 33 \text{ W}$	MIN.	2	mA
$V_{GT}$		MAX.	15	
$V_{GD}$		MAX.	1.3	V
$I_H$	$I_T = 100 \text{ mA}$ Gate open	MAX.	30	mA
$I_L$	$I_G = 1.2 I_{GT}$	MAX.	70	mA
dV/dt	$V_D = 67\% V_{DRM}$ Gate open	$T_j = 125^\circ\text{C}$	MIN.	150
$V_{TM}$	$I_{TM} = 16 \text{ A}$ tp = 380 $\mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.6
$V_{t0}$	Threshold voltage	$T_j = 125^\circ\text{C}$	MAX.	0.85
$R_d$	Dynamic resistance	$T_j = 125^\circ\text{C}$	MAX.	46
$I_{DRM}$	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$	MAX.	5
$I_{RRM}$		$T_j = 125^\circ\text{C}$	MAX.	2

### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	2.0	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient (DC)  $S = 0.5 \text{ cm}^2$	TO-220AB	60
		TO-263	70

S= copper surface under tab

### PRODUCT SELECTOR

Part Number	Voltage (xxx)	Sensitivity	Package
STYNX08S	200~1000	15 mA	TO-263
STYNX08	200~1000	15 mA	TO-220AB

### OTHER INFORMATION

Part Number	Marking	Weight	Base Quantity	Packing mode
STYNX08S	STYNX08S	1.50 g	50	Tube
STYNX08	STYNX08	1.90 g	50	Tube

Note: x = voltage

